Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material: |
|--|
| Glass |
| Overall Length: |
| Between 0.135 inches and 0.165 inches |
| Terminal Length: |
| 1.250 inches |
| Overall Diameter: |
| Between 0.050 inches and 0.070 inches |
| Mounting Method: |
| Terminal |
| Terminal Circle Diameter: |
| Between 0.017 inches and 0.023 inches |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 200.0 breakdown voltage, dc |
| Power Rating Per Characteristic: |
| 400.0 milliwatts any acceptable absolute |
| Capacitance Rating In Picofarads: |
| 0.5 |
| Maximum Operating Tempurature Per Measurement Point: |
| 150.0 degrees celsius ambient air |
| Terminal Type And Quantity: |
| 2 uninsulated wire lead |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |